

2SC5909

Silicon NPN triple diffusion mesa type

For horizontal deflection output

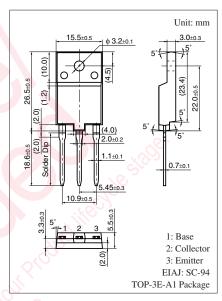
■ Features

- High breakdown voltage: $V_{CBO} \ge 1500 \text{ V}$
- High-speed switching: t_f < 200 ns
- Wide safe operation area

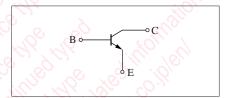
■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit		
Collector-base voltage (Emitter open)	V_{CBO}	1500	V		
Collector-emitter voltage (E-B short)	V _{CES}	1 500	V		
Collector-emitter voltage (Base open)	V _{CEO}	600 V			
Emitter-base voltage (Collector open)	V_{EBO}	7	7 V		
Base current	I_{B}	5	A		
Collector current	I_{C}	15	A		
Peak collector current *	I_{CP}	25 A			
Collector power dissipation	P _C	50	W		
$T_a = 25^{\circ}C$		3	40/10		
Junction temperature	T_{j}	150	°C vo		
Storage temperature	T_{stg}	-55 to +150	°C		

Note) *: Non-repetitive peak collector current



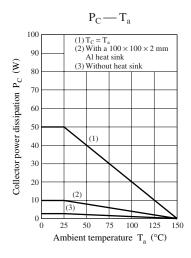
Internal Connection

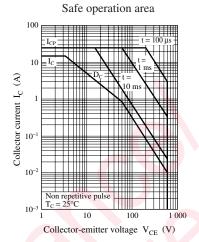


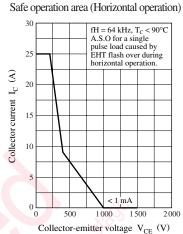
■ Electrical Characteristics $T_C = 25$ °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 1000 \text{ V}, I_E = 0$			50	μΑ
- Silo.		$V_{CB} = 1500 \text{ V}, I_E = 0$			1	mA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 7 \text{ V}, I_{C} = 0$			50	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 7.5 \text{ A}$	5		10	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 7.5 \text{ A}, I_B = 1.88 \text{ A}$			2.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 7.5 \text{ A}, I_B = 1.88 \text{ A}$			1.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ A}, f = 0.5 \text{ MHz}$		3		MHz
Storage time	t _{stg}	I _C = 7.5 A, Resistance loaded			2.7	μs
Fall time	t _f	$I_{B1} = 1.88 \text{ A}, I_{B2} = -3.75 \text{ A}$			0.2	μs

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.







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